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				Group Art Unit	2829
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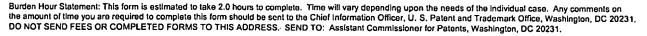
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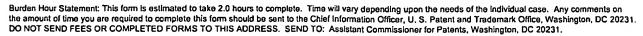
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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Application Number 10/771,023 Filing Date 3 February 2004 First Named Inventor HSIANG LAN LUNG Art Unit Not assigned Examiner Name Not assigned Attorney Docket Number MXIC 1564-1

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Examiner Initials*	Cite No.1	Document Number Number-Kind Code ^{2 (F known)}	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Unes, Whore Relevant Possages or Relevan Figures Appear
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